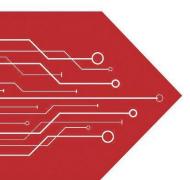
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Product data sheet

www.msksemi.com

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Features

Ultra low leakage: nA level Operating voltage: 5V Low clamping voltage

Complies with following standards:

– IEC 61000-4-2 (ESD) immunity test

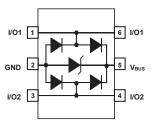
Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-4 (EFT) 40A (5/50ns)

-IEC61000-4-5 (Lightning) 6A (8/20µs)

RoHS Compliant





Applications

USB 2.0 interface 10/100 Ethernet Personal digital assistants (PDA's) Notebooks, Desktops and Servers Portable instrumentation Digital cameras

Mechanical Characteristics

Package: SOT23-6 Lead

Finish: Matte Tin

UL Flammability Classification Rating 94V-0 Pb-Free, Halogen Free, RoHS/WEEE Compliant

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	150	W	
Peak Pulse Current (8/20μs)	Ipp	6	А	
ESD per IEC 61000-4-2 (Air)	\/ E 0D	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	



Electrical Characteristics (T_A =25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse stand-off voltage	V_{RWM}				5	V
Reverse breakdown voltage	V_{BR}	I _{BR} =1mA	6		9	V
Reverse leakage current	I _R	V _R =5V			0.1	3 A
Clamping voltage (tp=8/203s)	Vc	I _{PP} =1A			10	V
Clamping voltage (tp=8/203s)	Vc	I _{PP} =6A			15	V
Junction capacitance	CJ	0Vdc,f=1MHz Between I/O pins and GND		0.8	1	pF
	Cı	0Vdc,f=1MHz I/O to I/O		0.35	0.4	pF

Typical Characteristics

Fig1. $8/20\mu$ s Pulse Waveform

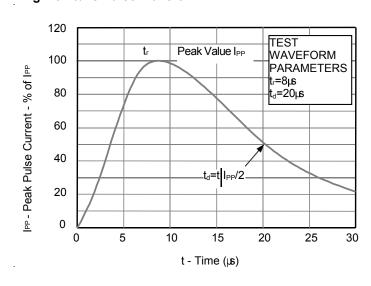


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

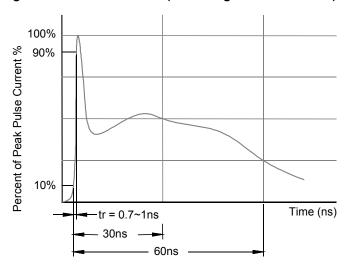
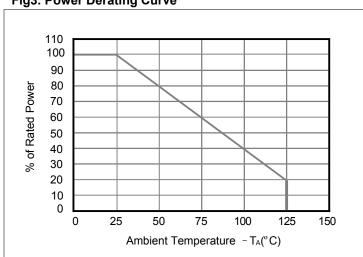
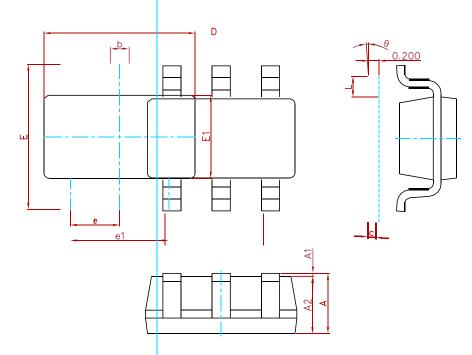


Fig3. Power Derating Curve

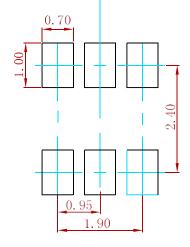






Symbol	Dimensions In Millimeters		Dimension	s In Inches
Syllibol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
 2. General tolerance:± 0.05mm.
 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MSUSBLC6-2SC6	SOT-23-6	3000



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Compiance

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